Elizaveta Semenova - DTU Orbit (30/04/2018)

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Publications:

Wavelength tunable MEMS VCSELs for OCT imaging
Publication: Research - peer-review › Article in proceedings – Annual report year: 2018

An ultra-efficient nonlinear planar integrated platform for optical signal processing and generation
Publication: Research - peer-review › Article in proceedings – Annual report year: 2018

A valence force field-Monte Carlo algorithm for quantum dot growth modeling
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

Characterization and optimization of a high-efficiency AlGaAs-On-Insulator-based wavelength converter for 64- and 256-QAM signals
Publication: Research - peer-review › Journal article – Annual report year: 2017

Demonstration of a self-pulsing photonic crystal Fano laser
Publication: Research - peer-review › Journal article – Annual report year: 2017

Enhancing Optical Forces in InP-Based Waveguides
Publication: Research - peer-review › Journal article – Annual report year: 2017

Experimental demonstration of a Fano laser based on photonic crystals
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

Fabrication and experimental demonstration of photonic crystal laser with buried heterostructure
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

High Q gallium nitride microring resonators
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

Hybrid Si-on-chip Lasers with Nano Structures
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2017

Lasers, switches and non-reciprocal elements based on photonic crystal Fano resonances
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017
Mid-IR optical properties of silicon doped InP
Publication: Research - peer-review › Journal article – Annual report year: 2017

On the high characteristic temperature of an InAs/GaAs/InGaAsP QD laser with an emission wavelength of ~1.5 μm on an InP substrate
Publication: Research - peer-review › Journal article – Annual report year: 2017

Photonic crystal Fano lasers and Fano switches
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

Photonic crystal Fano resonances for realizing optical switches, lasers and non-reciprocal elements
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

Specific features of waveguide recombination in laser structures with asymmetric barrier layers
Publication: Research - peer-review › Journal article – Annual report year: 2017

Towards Ultra-High Q Microresonators in High-Index Contrast AlGaAs-On-Insulator
Publication: Research - peer-review › Article in proceedings – Annual report year: 2017

Высокая характеристическая температура лазера на квантовых точках InAs/GaAs/InGaAsP с длиной волны излучения около 1.5 мкм, синтезированного на подложке InP
Publication: Research - peer-review › Journal article – Annual report year: 2017

1.5 μm InAs/InGaAsP/InP quantum dot laser with improved temperature stability
Publication: Research - peer-review › Conference article – Annual report year: 2016

An Ultra-Efficient Nonlinear Platform: AlGaAs-On-Insulator
Publication: Research - peer-review › Conference abstract for conference – Annual report year: 2016

Broadband and Efficient Dual-Pump Four-Wave Mixing in AlGaAs-On-Insulator Nano-Waveguide
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2016

Broadband and efficient dual-pump four-wave-mixing in AlGaAs-on-insulator nano-waveguides
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Characterization of a Wavelength Converter for 256-QAM Signals Based on an AlGaAs-On-Insulator Nano-waveguide
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Efficient frequency comb generation in AlGaAs-on-insulator
Publication: Research - peer-review › Journal article – Annual report year: 2016

Highly doped InP as a low loss plasmonic material for mid-IR region
Publication: Research - peer-review › Journal article – Annual report year: 2016

Low-loss high-confinement waveguides and microring resonators in AlGaAs-on-Insulator
Publication: Research - peer-review › Journal article – Annual report year: 2016

Nonlinear Optics in AlGaAs on Insulator
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Optically pumped 1550nm wavelength tunable MEMS VCSEL
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016
Phase-sensitive Four-wave Mixing in AlGaAs-on-Insulator Nano-waveguides
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Silicon doped InP as an alternative plasmonic material for mid-infrared
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Single-Source AlGaAs Frequency Comb Transmitter for 661 Tbit/s Data Transmission in a 30-core Fiber
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Supercontinuum Generation in AlGaAs-On-Insulator Nano-Waveguide at Telecom Wavelengths
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2016

Surface Plasmons on Highly Doped InP
Publication: Research - peer-review › Article in proceedings – Annual report year: 2016

Threshold Characteristics of Slow-Light Photonic Crystal Lasers
Publication: Research - peer-review › Journal article – Annual report year: 2016

Ultrahigh-speed Si-integrated on-chip laser with tailored dynamic characteristics
Publication: Research - peer-review › Journal article – Annual report year: 2016

Vertical-cavity laser with a novel grating mirror
Publication: Research › Ph.D. thesis – Annual report year: 2016

A Highly Efficient Nonlinear Platform: AlGaAs-On-Insulator
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2015

AlGaAs-On-Insulator Nanowire with 750 nm FWM Bandwidth, -9 dB CW Conversion Efficiency, and Ultrafast Operation Enabling Record Tbaud Wavelength Conversion
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

AlGaAs-On-Insulator nonlinear photonics
Publication: Research - peer-review › Conference abstract for conference – Annual report year: 2015

Diode lasers with asymmetric barriers for 850 nm spectral range: experimental studies of power characteristics
Publication: Research - peer-review › Journal article – Annual report year: 2015

Highly Efficient Four-Wave Mixing in an AlGaAs-On-Insulator (AlGaAsOI) Nano-Waveguide
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Highly Sensitive Photonic Crystal Cavity Laser Noise Measurements using Bayesian Filtering
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Hybrid III-V/SOI single-mode vertical-cavity laser with in-plane emission into a silicon waveguide
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Hybrid vertical-cavity laser with lateral emission into a silicon waveguide
Publication: Research - peer-review › Journal article – Annual report year: 2015
III-V/SOI vertical cavity laser structure for 120 Gbit/s speed
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

III-V/SOI vertical cavity laser with in-plane output into a Si waveguide
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Improvement of power characteristics in 850 nm quantum well laser with asymmetric barriers
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

On the optimization of asymmetric barrier layers in InAlGaAs/AlGaAs laser heterostructures on GaAs substrates
Publication: Research - peer-review › Journal article – Annual report year: 2015

Overcoming doping limits in MOVPE grown n-doped InP for plasmonic applications
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Slow-light effects in photonic crystal membrane lasers
Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Suppression of sublinearity of light–current curve in 850 nm quantum well laser with asymmetric barrier layers
Publication: Research - peer-review › Journal article – Annual report year: 2015

Tailoring quantum structures for active photonic crystals
Publication: Research › Ph.D. thesis – Annual report year: 2015

The effect of asymmetric barrier layers in the waveguide region on power characteristics of QW lasers
Publication: Research - peer-review › Journal article – Annual report year: 2015

Thermal analysis of line-defect photonic crystal lasers
Publication: Research - peer-review › Journal article – Annual report year: 2015

Publication: Research - peer-review › Article in proceedings – Annual report year: 2015

Butt-Joint Integration of active optical components based on InP/AlInGaAsP alloys
Publication: Research - peer-review › Article in proceedings – Annual report year: 2014

Crystallographic dependent in-situ CBr4 selective nano-area etching and local regrowth of InP/InGaAs by MOVPE
Publication: Research - peer-review › Journal article – Annual report year: 2014

Epitaxial growth of quantum dots on InP for device applications operating at the 1.55 μm wavelength range
Publication: Research - peer-review › Conference article – Annual report year: 2014

High-quality MOVPE butt-joint integration of InP/AlGaInAs/InGaAsP-based all-active optical components
Publication: Research - peer-review › Journal article – Annual report year: 2014

Improvement of light-current characteristic linearity in a quantum well laser with asymmetric barriers
Publication: Research - peer-review › Article in proceedings – Annual report year: 2014

Material Engineering for Monolithic Semiconductor Mode-Locked Lasers
Publication: Research › Ph.D. thesis – Annual report year: 2014
Nonplanar nanoselective area growth of InGaAs/InP
Publication: Research - peer-review › Conference article – Annual report year: 2014

Slow-light-enhanced gain in active photonic crystal waveguides
Publication: Research - peer-review › Journal article – Annual report year: 2014

1060-nm Tunable Monolithic High Index Contrast Subwavelength Grating VCSEL
Publication: Research - peer-review › Journal article – Annual report year: 2013

Crystallographic dependence of the lateral undercut wet etch rate of Al$_{0.5}$In$_{0.5}$P in diluted HCl for III-V sacrificial release
Publication: Research - peer-review › Journal article – Annual report year: 2013

Hybrid III-V-on-Si Vertical Cavity laser for Optical Interconnects
Publication: Research - peer-review › Article in proceedings – Annual report year: 2014

Resonant MEMS tunable VCSEL
Publication: Research - peer-review › Journal article – Annual report year: 2013

Ultrahigh-speed hybrid laser for silicon photonic integrated chips
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2014

41 GHz and 10.6 GHz low threshold and low noise InAs/InP quantum dash two-section mode-locked lasers in L band
Publication: Research - peer-review › Journal article – Annual report year: 2012

Effect of Asymmetric Barrier Layers in the Waveguide Region on the Temperature Characteristics of QuantumWell Lasers
Publication: Research - peer-review › Journal article – Annual report year: 2012

Enhanced Gain in Photonic Crystal Amplifiers
Publication: Research - peer-review › Article in proceedings – Annual report year: 2012

High-speed photodetectors in a photonic crystal platform
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2012

Improvement of temperature-stability in a quantum well laser with asymmetric barrier layers
Publication: Research - peer-review › Journal article – Annual report year: 2012

Individual optimization of InAlGaAsP-InP sections for 1.55-μm passively mode-locked lasers
Publication: Research - peer-review › Journal article – Annual report year: 2012

Nano-selective area growth of InGaAs/InP using CBr$_4$ insitu etching
Publication: Research - peer-review › Article in proceedings – Annual report year: 2012

Slow-light enhancement of spontaneous emission in active photonic crystal waveguides
Publication: Research - peer-review › Conference article – Annual report year: 2012

Active III-V Semiconductor Photonic Crystal Waveguides
Publication: Research - peer-review › Article in proceedings – Annual report year: 2011

Enhanced Gain in Slow-Light Photonic Crystal Waveguides with Embedded Quantum Dots
Publication: Research - peer-review › Article in proceedings – Annual report year: 2011
InAs/InGaAsP Quantum Dots Emitting at 1.5 μm for Applications in Lasers
Publication: Research - peer-review › Article in proceedings – Annual report year: 2011

Investigating the chemical and morphological evolution of GaAs capped InAs/InP quantum dots emitting at 1.5μm using aberration-corrected scanning transmission electron microscopy
Publication: Research - peer-review › Journal article – Annual report year: 2011

Metal organic vapor-phase epitaxy of InAs/InGaAsP quantum dots for laser applications at 1.5 μm
Publication: Research - peer-review › Journal article – Annual report year: 2011

Quantitative strain mapping of InAs/InP quantum dots with 1 nm spatial resolution using dark field electron holography
Publication: Research - peer-review › Journal article – Annual report year: 2011

Towards quantitative three-dimensional characterisation of buried InAs quantum dots
Publication: Research - peer-review › Conference article – Annual report year: 2011

Towards quantitative three-dimensional characterisation of InAs quantum dots
Publication: Research - peer-review › Conference abstract in proceedings – Annual report year: 2011

10-GHz 1.59-μm quantum dash passively mode-locked two-section lasers
Publication: Research - peer-review › Conference article – Annual report year: 2011

Lambda shifted photonic crystal cavity laser
Publication: Research - peer-review › Journal article – Annual report year: 2010

Quarter-lambda-shifted photonic crystal lasers
Publication: Research - peer-review › Poster – Annual report year: 2010

Projects:

III-V Nanowire Selective Area MOVPE Growth for High Efficiency Solar Cell
Project: PhD

Tailored nanoscale optical materials and devices
Project: PhD

Developing of Superior Quantum Dot Gain Material for 1.5-1.6 um Wavelength Range
Project: PhD

Developing of III-V epitaxy of highly efficient quantum dot gain material to the silicon platform
Project: PhD

Block Copolymer Precursors for Chemical Nanopatterning of Graphene
Project: PhD

Design and fabrication of mid-infrared plasmonic materials based on highly doped III-V semiconductors
Project: PhD

Quantum dot Energy level Engineering for laser applicatioNs on InP and Si platforms
Project
Vertical-cavity laser with a novel grating mirror
Project: PhD

QDLaser: Development of novel quantum dot based materials for compact laser devices for potential
Project

Nanoscale semiconductor optical devices
Project: PhD

Femtosecond semiconductor lasers
Project: PhD

Femtosecond semiconductor LASers Harnessed
Project

Governing the speed of light
Project

Activities:

Presentation title: "A valence force field-Monte Carlo algorithm for quantum dot growth modeling".
Activity: Talks and presentations » Conference presentations